

# **Quad Monolithic SPST CMOS Analog Switches**

#### **DESCRIPTION**

Featuring low on-resistance (60  $\Omega$ ) and fast switching (130 ns), the DG308A is supplied in the "normally open" configuration while DG309 is supplied "normally closed". Input thresholds are high voltage CMOS compatible.

Designed with the Vishay Siliconix PLUS-40 CMOS process to combine low power dissipation with a high breakdown voltage rating of 44 V, each switch conducts equally well in both directions when on, and blocks up to the supply voltage when off. An epitaxial layer prevents latch up.

The DG308B, DG309B upgrades are recommended for new designs.

## **FEATURES**

• ± 15 V analog input range

Low on-resistance: 60 Ω
Fast switching: 130 ns

• Low power dissipation: 30 nW

CMOS logic compatible

# Pb-free Available



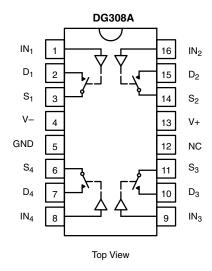
#### **BENEFITS**

- Full rail-to-rail analog signal range
- · Low signal error
- Wide dynamic range
- Single or dual supply capability
- Static protected logic inputs
- Space savings (TSSOP)

#### **APPLICATIONS**

- Portable and battery powered instrumentation
- · Communication systems
- · Computer peripherals
- · High-speed multiplexing

#### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**



For SPST Switches per Package

TRUTH TABLE								
Logic	Logic DG308A DG309							
0	OFF	ON						
1	ON	OFF						

 $\label{eq:logic "0" leq 3.5 V} \mbox{Logic "1" leq 11 V} \\ \mbox{Logic "1" leq 11 V} \\ \mbox{}$ 

<sup>\*</sup> Pb containing terminations are not RoHS compliant, exemptions may apply

# Vishay Siliconix



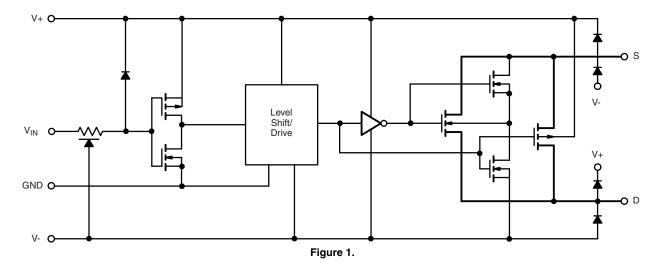
ORDERING INFORMATION				
Temp. Range	Package	Part Number		
		DG308ACJ		
0 °C to 70 °C	16-Pin Plastic DIP	DG308ACJ-E3		
0 0 10 70 0	101 III lastic bii	DG309CJ		
		DG309CJ-E3		
		DG308ADY		
		DG308ADY-E3		
		DG308ADY-T1		
	16-Pin Narrow SOIC	DG308ADY-T1-E3		
	10 1 III Nanow COIO	DG309DY		
		DG309DY-E3		
		DG309DY-T1		
- 40 °C to 85 °C		DG309DY-T1-E3		
40 0 10 00 0		DG308ADQ		
		DG308ADQ-E3		
		DG308ADQ-T1		
	16-Pin TSSOP	DG308ADQ-T1-E3		
	10-1 111 1 3001	DG309DQ		
		DG309DQ-E3		
		DG309DQ-T1		
		DG309DQ-T1-E3		

ABSOLUTE MAXIMUM RATINGS					
Parameter		Limit	Unit		
Voltages Referenced V+ to V	V-	44			
GND		25	V		
Digital Inputs <sup>a</sup> , V <sub>S</sub> , V <sub>D</sub>		(V-) - 2 to (V+) + 2 or 20 mA, whichever occurs first			
Current, Any Terminal Excep	ot S or D	30			
Continuous Current	S or D	20	mA		
Continuous Current	(Pulsed at 1 ms, 10 % duty cycle max.)	70			
Ctorogo Tomporoturo	(AK Suffix)	- 65 to 150	°C		
Storage Temperature	(CJ, DY and DQ Suffix)	- 65 to 125			
	16-Pin Plastic DIP <sup>c</sup>	470			
Power Dissipation <sup>b</sup>	16-Pin Narrow SOIC and TSSOP <sup>e</sup>	600	mW		
	16-Pin CerDIP <sup>d</sup>	900			

- Notes: a. Signals on  $S_X$ ,  $D_X$ , or  $IN_X$  exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 12 mW/°C above 75 °C.
- d. Derate 6.5 mW/°C above 25 °C.
- e. Derate 7.6 mW/°C above 75 °C.



# **SCHEMATIC DIAGRAM** (Typical Channel)



SPECIFICATIONS <sup>a</sup>									
		Test Conditions Unless Specified V+ = 15 V, V- = - 15 V			<b>A Suffix</b> - 55 °C to 125°C		C, D Suffix		
Parameter	Symbol	$V_{IN} = 3.5 \text{ V or } 11 \text{ V}^f$	Temp.b	Typ. <sup>c</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Min.d	Max. <sup>d</sup>	Unit
Analog Switch			•						
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full		- 15	15	- 15	15	V
Drain-Source On-Resistance	R <sub>DS(on)</sub>	$V_D = \pm 10 \text{ V}, I_S = 1 \text{ mA}$	Room Full	60		100 150		100 125	Ω
Source Off Leakage Current	I <sub>S(off)</sub>	$V_S = \pm 14 \text{ V}, V_D = \pm 14 \text{ V}$	Room Full	± 0.1	- 1 100	1 100	- 5 - 100	5 100	
Drain Off Leakage Current	I <sub>D(off)</sub>	$V_D = \pm 14 \text{ V}, V_S = \pm 14 \text{ V}$	Room Full	± 0.1	- 1 100	1 100	- 5 - 100	5 100	nA
Drain On Leakage Current	I <sub>D(on)</sub>	$V_D = V_S = \pm 14 \text{ V}$	Room Full	± 0.1	- 1 100	1 100	- 5 - 200	5 200	
Digital Control									
Input Current with Input Voltage High	I <sub>INH</sub>	V <sub>IN</sub> = 15 V	Full	0.001		1		1	μΑ
Input Current with Input Voltage Low	I <sub>INL</sub>	V <sub>IN</sub> = 0 V	Full	- 0.001	- 1		- 1		μΛ
Input Capacitance	C <sub>IN</sub>		Room	8					pF
Dynamic Characteristics									
Turn-On Time	t <sub>ON</sub>	see figure 2	Room	130		200		200	ns
Turn-Off Time	t <sub>OFF</sub>	300 ligare 2	Room	90		150		150	113
Charge Injection	Q	$C_L = 0.01 \mu F, R_{gen} = 0 \Omega, V_{gen} = 0 V,$	Room	- 10					рС
Source-Off Capacitance	C <sub>S(off)</sub>		Room	11					
Drain-Off Capacitance	C <sub>D(off)</sub>	$f = 140 \text{ kHz}, V_S, V_D = 0 \text{ V}$	Room	8					pF
Channel-On Capacitance	C <sub>D(on)</sub>		Room	27					
Off-Isolation <sup>†</sup>	OIRR	$R_L = 75 \Omega$ , $V_S = 2 V_{p-p}$ , $f = 500 \text{ kHz}$	Room	78				_	dB

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SPECIFICATIONS <sup>a</sup>									
		Test Conditions Unless Specified V+ = 15 V, V- = - 15 V			_	uffix to 125°C	C, D	Suffix	
Parameter	Symbol	$V_{IN} = 3.5 \text{ V or } 11 \text{ V}^f$	Temp.b	Typ.c	Min.d	Max. <sup>d</sup>	Min.d	Max.d	Unit
Power Supplies									
Positive Supply Current	I+	all channels on or off	Room Full	0.001		10 100		10 100	
Negative Supply Current	I-	V <sub>IN</sub> = 0 V or 15 V	Room Full	- 0.001	- 10 - 100		- 100		μΑ

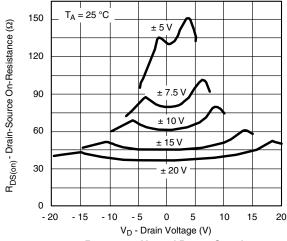
#### Notes:

- a. Refer to PROCESS OPTION FLOWCHART.
- b.Room = 25  $^{\circ}$ C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e.Guaranteed by design, not subject to production test.
- f.  $V_{IN}$  = input voltage to perform proper function.

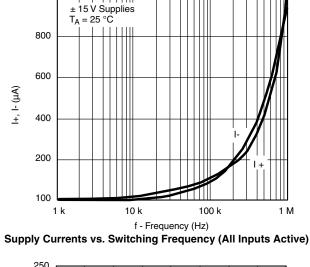
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

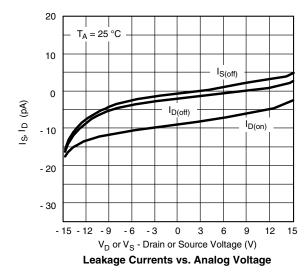
1000

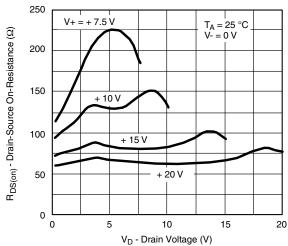
# TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



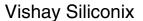
R<sub>DS(on)</sub> vs. V<sub>D</sub> and Power Supply





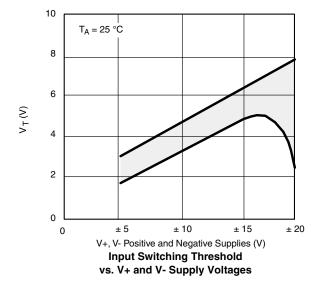


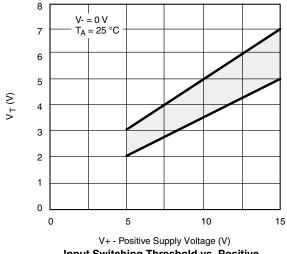
 $R_{DS(on)}$  vs.  $V_D$  and Power Supply Voltage



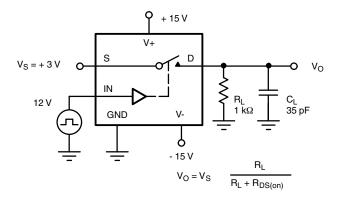


# TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





Input Switching Threshold vs. Positive
Supply Voltage



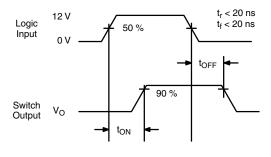


Figure 2. Switching Time

## **APPLICATIONS**

# **Single Supply Operation**

The DG308A and DG309 will switch positive analog signals while using a single positive supply. This will allow use in many applications where only one supply is available. The trade-offs or performance given up while using single supplies are:

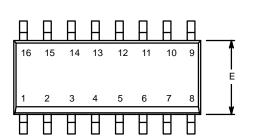
1) increased  $R_{DS(on)}$  and 2) slower switching speed. As stated in the absolute maximum ratings section of the data sheet, the analog voltage should not go above or below the supply voltages which in single supply operation are V+ and 0 V.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="https://www.vishay.com/ppg?70046">www.vishay.com/ppg?70046</a>.





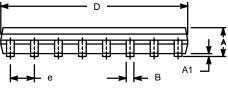
SOIC (NARROW): 16-LEAD JEDEC Part Number: MS-012

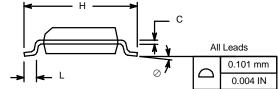


	MILLIMETERS		INC	HES			
Dim	Min	Max	Min	Max			
Α	1.35	1.75	0.053	0.069			
A <sub>1</sub>	0.10	0.20	0.004	0.008			
В	0.38	0.51	0.015	0.020			
С	0.18	0.23	0.007	0.009			
D	9.80	10.00	0.385	0.393			
E	3.80	4.00	0.149	0.157			
е	1.27	BSC	0.050	BSC			
Н	5.80	6.20	0.228	0.244			
L	0.50	0.93	0.020	0.037			
0	0°	8°	0°	8°			
FCN: S-0	FCN: S-03946—Rev F 09-Jul-01						

ECN: S-03946—Rev. F, 09-Jul-01

DWG: 5300

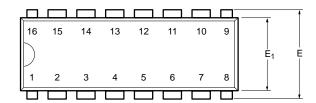


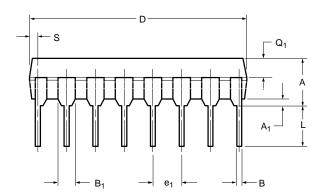


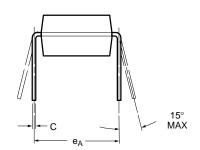
www.vishay.com 02-Jul-01



PDIP: 16-LEAD





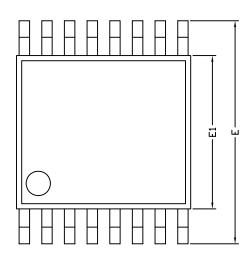


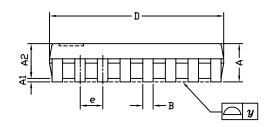
	MILLIN	IETERS	INC	HES		
Dim	Min	Max	Min	Max		
Α	3.81	5.08	0.150	0.200		
A <sub>1</sub>	0.38	1.27	0.015	0.050		
В	0.38	0.51	0.015	0.020		
B <sub>1</sub>	0.89	1.65	0.035	0.065		
С	0.20	0.30	0.008	0.012		
D	18.93	21.33	0.745	0.840		
E	7.62	8.26	0.300	0.325		
E <sub>1</sub>	5.59	7.11	0.220	0.280		
e <sub>1</sub>	2.29	2.79	0.090	0.110		
e <sub>A</sub>	7.37	7.87	0.290	0.310		
L	2.79	3.81	0.110	0.150		
Q <sub>1</sub>	1.27	2.03	0.050	0.080		
S	0.38	1.52	.015	0.060		
ECN: S-03946—Rev. D, 09-Jul-01 DWG: 5482						

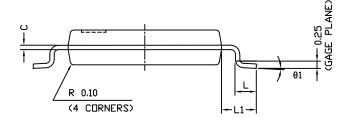
Document Number: 71261 www.vishay.com 06-Jul-01



**TSSOP: 16-LEAD** 







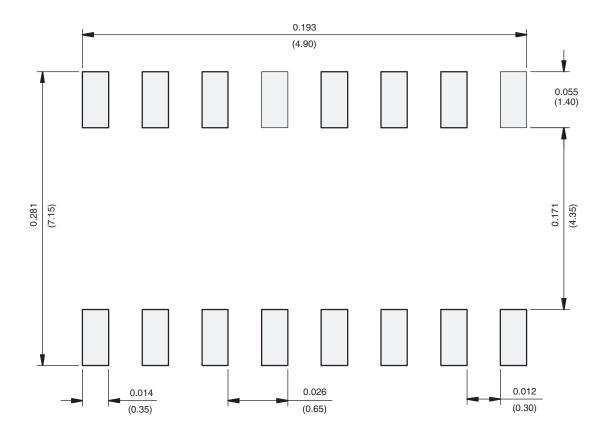
	DII	MENSIONS IN MILLIMETE	RS
Symbols	Min	Nom	Max
А	=	1.10	1.20
A1	0.05	0.10	0.15
A2	=	1.00	1.05
В	0.22	0.28	0.38
С	=	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
е	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
у	=	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D. 23-0	Oct-06	<u> </u>	

DWG: 5624

Document Number: 74417 www.vishay.com 23-Oct-06



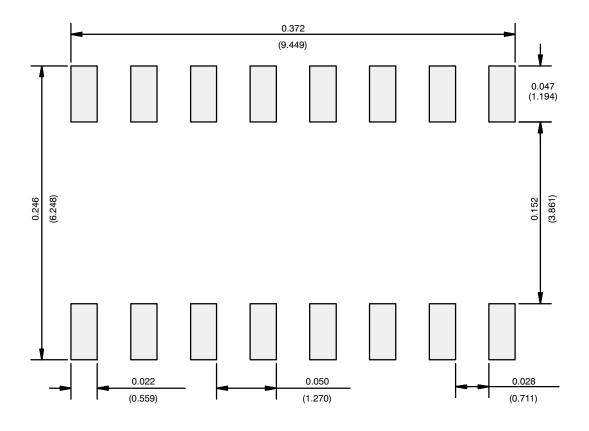
# **RECOMMENDED MINIMUM PAD FOR TSSOP-16**



Recommended Minimum Pads Dimensions in inches (mm)



# **RECOMMENDED MINIMUM PADS FOR SO-16**



Recommended Minimum Pads Dimensions in Inches/(mm)

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